

CCD multichannel detector heads



C7040

C7041

Designed for back-thinned CCD area image sensor

The C7040 and C7041 are high sensitivity multichannel detector heads for use with back-thinned CCD area image sensors (S7030/ S7031 series, etc.) that offer high UV sensitivity and quantum efficiency. The C7040 is designed for the non-cooled type (S7030 series, S16000-1007), while the C7041 for the one-stage TE-cooled type (S7031 series, S16001-1007S) for detection at even lower light levels. Both the C7040 and C7041 incorporate a low-noise driver/amplifier circuit that provides reliable operation from simple external signals. The C7041 also includes a highly stable temperature controller that cools the sensor to a preset temperature level (Tchip=-10 °C) as soon as the power is turned on. If the cooler fails and causes internal circuitry to overheat, the built-in protection circuit automatically turns off the power to the thermoelectric cooler. Despite its compact size, the housing configuration is designed for good heat dissipation, and threaded mounting holes on the front panel allow connections to other devices such as monochrometers. The table (P.2) shows back-thinned CCD image sensors for the C7040 and C7041. The C7040 and C7041 do not come with a CCD image sensor, so select the desired sensor and order it separately.

The controller for multichannel detector head C7557-01 is also available. The software supplied with the C7557-01 allows easy control of the multichannel detector head and data acquisition.

Features

- Designed for back-thinned CCD area image sensor*¹ C7040: for non-cooled type (S7030 series, S16000-1007) C7041: for TE-cooled type (S7031 series, S16001-1007S)
- → Line binning operation*2/area scanning operation
- Driver/amplifier circuit for low noise CCD operation
- Highly stable temperature controller (C7041)
- **■** Simple signal input operation
- → Compact configuration

- Applications

- **■** Fluorescence spectroscopy
- Raman spectroscopy
- **■** Other low-light-level detection

- *1: In normal CCD image sensors that receive light from the front surface, the active area is covered with electrodes for charge transfer. These electrodes cut off UV radiation incident on the image sensor and also reduce the quantum efficiency. In contrast, back-thinned CCD image sensors have a unique structure in which the back of the active area is finely ground to allow light to enter from the back surface. This structure ensures high UV sensitivity and quantum efficiency because incident light need not pass through the electrodes.
- *2: The CCD area image sensor can be operated like a linear image sensor having a large active area by transferring all the pixel signals in the vertical direction to the horizontal register (this is referred to as line binning).

Selection guide

The table below shows CCD area image sensors applicable for the C7040 and C7041. Since the C7040 and C7041 do not include a CCD area image sensor, so select the desired sensor and order it separately.

	CCD area image sensor						
Type no.	Type no.	Number of pixels	Number of effective pixels	Image area $[mm (H) \times mm (V)]$			
	S7030-0906	532 × 64	512 × 58	12.288×1.392			
	S7030-0907	532 × 128	512 × 122	12.288×2.928			
C7040	S7030-1006	1044 × 64	1024 × 58	24.576 × 1.392			
	S7030-1007	1044 × 128	1024 × 122	24.576 × 2.928			
	S16000-1007	1044 × 128	1024 × 122	24.576 × 2.928			
	S7031-0906S	532 × 64	512 × 58	12.288×1.392			
	S7031-0907S	532 × 128	512 × 122	12.288×2.928			
C7041	S7031-1006S	1044 × 64	1024 × 58	24.576 × 1.392			
	S7031-1007S	1044 × 128	1024 × 122	24.576 × 2.928			
	S16001-1007S	1044 × 128	1024 × 122	24.576 × 2.928			

Note: CCD multichannel detector head C7042 for two-stage TE-cooled CCD area image sensor S7032 series is also available.

- Absolute maximum ratings

Parameter		Symbol	Min.	Тур.	Max.	Unit	
Supply voltage (for digital circuitry)		V _{D1}	-0.5	-	+7		
Supply voltage (for analog circuitry)		VA1+	-	-	+18		
		VA1-	-	-	-18		
		VA2	-	-	+30	V	
Supply voltage*3		VD2	-	-	+7		
		Vp	-	-	+7		
		VF	-	-	+14		
Digital input voltage		-	-	-	VD (1, 2)		
Operating temperature*4	C7040	Topr	0	-	+50	°C	
	C7041		+10	-	+30		
Storage temperature*4	C7040	Tstg	-20	-	+70	-C	
	C7041		0	-	+50		

^{*3:} C7041

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.



^{*4:} No dew condensation

= Electrical characteristics

(Ta=25 °C, VD1=+5 V, VA1+=+15 V, VA1-=-15 V, VA2=+24 V, VD2=+5 V, Vp=+5 V, VF=+12 V, unless otherwise noted)

Parameter		Symbol	Min.	Тур.	Max.	Unit
Didital Innit	High level	VIH	+2.0	-	VD (1, 2)	V
	Low level	VIL	-0.5	-	+0.8	V
CLK frequency	,	fclk	-	-	1	MHz
Data video rea	adout frequency	fv	-	-	fclk/4	Hz
Start pulse wie	dth	tst	1/fclk	-	-	S
Digital output	High level (Io=-6 mA)	VIH	+2.0	-	-	V
Digital output	Low level (Io=+6 mA)	VIL	-	-	+0.8	V
Power supply	operating conditions					
	Digital circuitry*5	V _{D1}	+4.75	+5.0	+5.25	V
		VA1+	+14.75	+15.0	+15.25	V
Voltage	Analog circuitry	VA1-	-14.75	-15.0	-15.25	V
		VA2	+23.75	+24.0	+24.25	V
	Other* ⁵	VD2	+4.75	+5.0	+5.25	V
		Vp	+4.75	+5.0	+5.25	V
		VF	+11.75	+12.0	+12.25	V
Current	VD1 (+5 VDC)	-	-	-	+200	mA
	Va1+ (+15 VDC)	-	-	-	+100	mA
	Va1- (-15 VDC)	-	-	-	-100	mA
	Va2 (+24 VDC)	-	-	-	+30	mA
	V _{D2} (+5 VDC)* ⁵	-	-	-	+30	mA
	Vp (+5 DC)*5	-	-	-	+2.5	Α
	VF (+12 VDC)*5	-	-	-	+150	mA

^{*5:} C7041

Electrical and optical characteristics

(Ta=25 °C, Tchip=-10 °C, VD1=+5 V, VA1+=+15 V, VA1-=-15 V, VA2=+24 V, VD2=+5 V, Vp=+5 V, VF=+12 V)

Parameter		Symbol	Min	Тур.	Max.	Unit
Spectral response range		λ	-	200 to 1100		nm
	Vertical	Fw	240	320	-	ke ⁻
Full well capacitiy			200*6	280* ⁶	-	
	Horizontal		800	1000	-	
Conversion gain*7		Sv	-	15	-	μV/e-
Saturation output voltage		Vsat	10	-	-	V
	C7040 (Tchip=25 °C)	- DS	-	100	1000	e ⁻ /pixel/s
Dark current*8			-	200*9	1000*9	
Dark Current	C7041 (Tchip=-10 °C)		-	3	30	
			-	6* ¹⁰	30* ¹⁰	
Readout noise		Nread	-	20	-	e- rms
Dynamic range		Drange	-	50000*11	-	-
Photoresponse nonuniformity*12		PRNU	-	±3	±10	%

^{*6:} S16000-1007, S16001-1007S



^{*7:} Including the circuit gain

^{*8:} At MPP mode. Vertical resiter value. The actual value equals the sum of the vertical direction because of the binning operation.

^{*9:} S16000-1007

^{*10:} S16001-1007S

^{*11:} During line binning

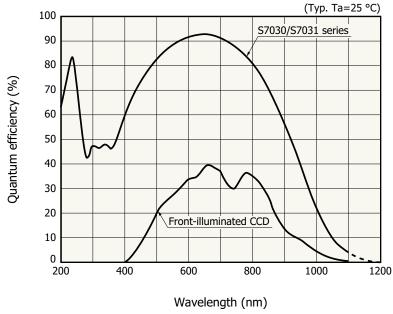
^{*12:} Measured at 50% of the full well capacity

■ Specifications for temperature controller (C7041) (Ta=25 °C, VD1=+5 V, VA1+=+15 V, VA1-=-15 V, VA2=+24 V, VD2=+5 V, Vp=+5 V, VF=+12 V)

Parameter*13	Symbol	Min.	Тур.	Max.	Unit
Cooling temperature	Ts	-11.5	-10	-8.5	°C
Temperature control range	ΔTs	-0.05	-	+0.05	°C
Power dissipation of TE-cooler element	Рр	-	-	7	W
Cool down time to reset temperature	to	-	-	5	min
Setting temperature for overheat protection*14	То	-	+45	-	°C

^{*13:} Other functions include error display, automatic power off, and detection of electrical opens and shorts by the thermosensor.

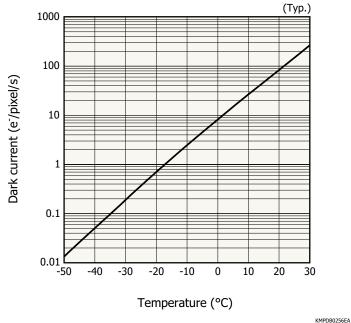
Spectral response (without window)



KMPDB0038EC

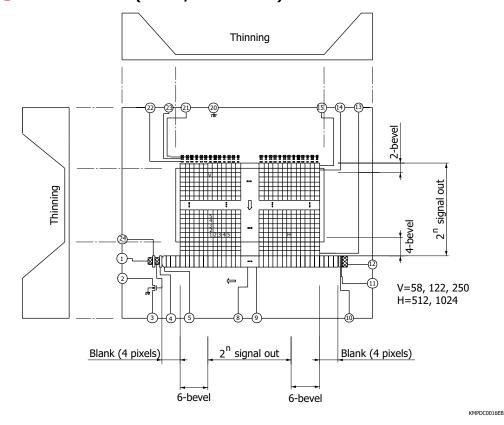
^{*14:} Temperature on the rear of the case (where the fan is installed)

Dark current vs. temperature

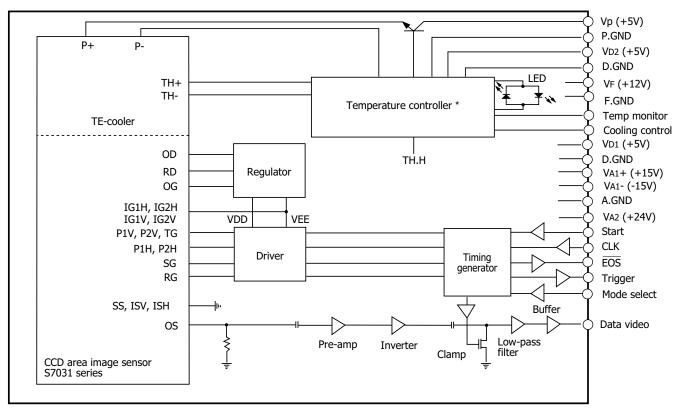


KMPDB0250EA

▶ Device structure (S7030/S7031 series)



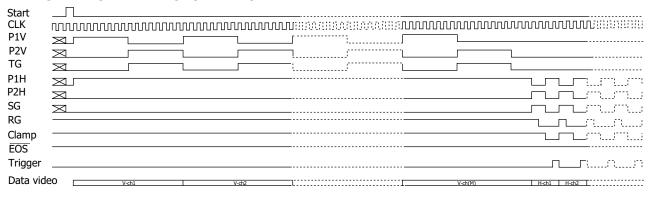
Block diagram (C7041)

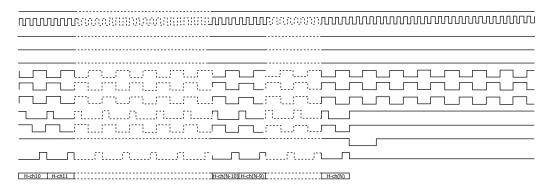


^{*} The C7040 does not include the temperature controller and TE-cooler.

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Timing chart (line binning operation)



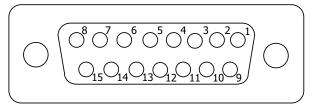


M=64, 128, 256 N=532, 1044 V-ch1--V-ch2, V-ch (M-3)--V-ch (M): Isolation pixels H-ch1--H-ch4, H-ch (N-3)--H-ch (N): Blank pixels H-ch5--H-ch10, H-ch (N-9)--H-ch (N-4): Isolation pixels



⇒ Pin connections of "SIGNAL I/O" connector

15-pin D-sub connector

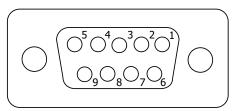


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Pin no.	Terminal name	Description
1	Mode select	Digital input signal used to select between the line binning operation and area scanning operation. HCMOS compatible. High level or left open: line binning operation Low level: area scanning operation
2	Data video	Analog video output. Positive polarity.
3	VA1+ (+15 V)	Analog power supply
4	VA1- (-15 V)	Analog power supply
5	VD1 (+5 V)	Digital power supply
6	Start	Digital input signal for initializing the circuit. HCMOS compatible. Positive logic. The interval of the Start pulses determines the integration time of the CCD image sensor.
7	CLK	Digital input signal for operating the circuit. HCMOS compatible. Rising edge operation.
8	EOS	Digital output signal for indicating end-of-scan of the image sensor. HCMOS compatible. Negative logic.
9	A.GND	Analog ground
10	A.GND	Analog ground
11	VA2 (+24 V)	Analog power supply
12	D.GND	Digital ground
13	D.GND	Digital ground
14	D.GND	Digital ground
15	Trigger	Digital output signal for A/D conversion. HCMOS compatible. Positive logic.

➡ Pin connections of "TE CONTROL I/O" connector (C7041)

9-pin D-sub connector



KACCC0075EA

Pin no.	Terminal name	Description
1	VD2 (+5 V)	Digital power supply
2	Temp monitor	Analog output signal of the temperature of the CCD image sensor
3	Cooling control	Digital input signal for starting to cool down. HCMOS compatible. High level or left open: cooling Low level: stand-by
4	Vp (+5 V)	Power supply for the thermoelectric cooler in the CCD image sensor (Please use AWG 18 wire)
5	VF (+12 V)	Power supply for cooling fan
6	D.GND	Ground
7	D.GND	Ground
8	P.GND	Power supply return of the thermoelectric cooler mounted in the CCD image sensor (Please use AWG 18 wire)
9	F.GND	Power supply return for cooling fan

Available for using same power supply (+5 V) for "+VD2" and "+VP"

Caution: Do not connect "VD2" and "Vp" together on the backside of the 9-pin D-sub connector.

These may be connected (shorted) at the power supply end, not 9-pin D-sub connector.

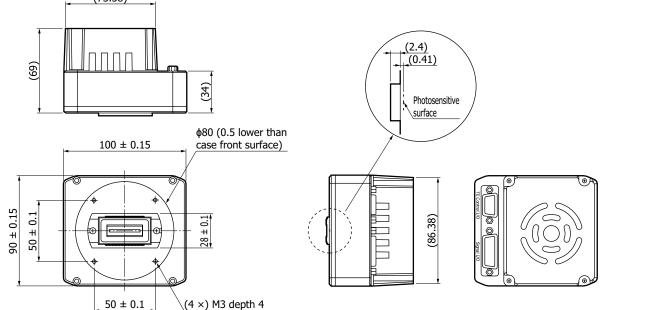


Dimensional outlines (unit: mm)

C7040 (1.9) (0.55) 34) Photosensitive surface φ80 (0.5 lower than case front surface) 100 ± 0.15 62 ± 0.2 **①** 90 ± 0.15 50 ± 0.1 82 ± 0.1 28 ± 0.1 **⊕** 0 50 ± 0.1 (4 ×) M3 depth 4 Weight: approx. 550 g (sensor included) Note: The sensor is sold separately.

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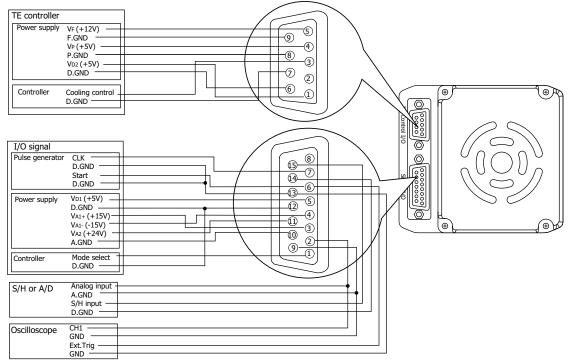
C7041



Weight: approx. 700 g (sensor included) Note: The sensor is sold separately.

KACCA0063EF

Pin connections (C7041)



KACCC0076EE

- Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- · Disclaimer

Multichannel detector head controller C7557-01

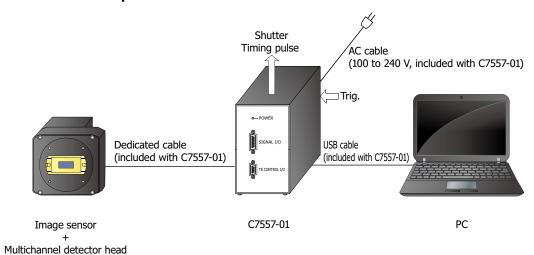
When connected to a HAMAMATSU multichannel detector head and a personal computer, the C7557-01 allows easy control of the detector head and data acquisition by using dedicated software that comes with the unit.

- Accessories for C7557-01

- · Spare fuse (2.5 A)*15
- · AC cable
- · 2 to 3 conversion adapter
- · USB cable
- · Detector head connection cables
- (for "SIGNAL I/O" and "TE CONTROL I/O" terminal of multichannel detector head)
- · CD-R (MCD USB driver, software, operation manual)
- MOS adapter*¹⁶
- *15: Contained in the holder just above the AC cable connector on the C7557-01 rear panel.
- *16: For connection of NMOS multichannel detector head. Do not use for CCD multichannel detector head. It can cause abnormal operation.



Connection example



Note: Shutter, etc. are not available.

KACCC0402EI

Information described in this material is current as of June 2023.

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